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TECHNOLOGY CENTER 2800
Attorney Docket SEL 173

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of

Ohtani et al.

Serial No.: 09/535,836

Filed: March 28, 2000

For: Semiconductor Device Having
Multi-layer Wiring

Art Unit: 2811

Examiner: H. Vu

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to:

Commissioner for Patents
Washington, D.C. 20231

on November 12, 2002

Rachelle Hammerquist

[Signature] 11-12-02
Signature Date

Commissioner for Patents
Washington, D.C. 20231

AMENDMENT E

Sir:

In response to the Office Action dated August 14, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

Please amend the claims as follows:

28. (Third Amendment) A semiconductor device comprising:

a thin film transistor formed over a substrate, said thin film transistor having a semiconductor layer and a gate electrode adjacent to said semiconductor layer with a gate insulating film interposed therebetween;

a first insulating film comprising an organic material formed over said thin film transistor;

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